

# JS12U1GD50-3

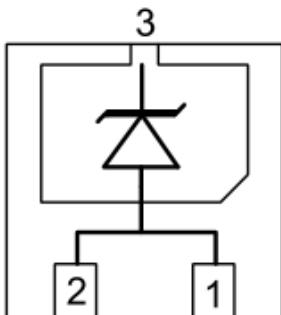
## 1-Line Uni-directional High Power TVS Diode



### Description

The JS12U1GD50-3 is a high power TVS, utilizing leading monolithic silicon technology to provide fast response time and low ESD clamping voltage, making this device an ideal solution for protecting voltage sensitive lines.. It is assembled into a 3-pin DFN2020-3 lead-free package. The leads are finished with NiPdAu. Each device will protect one line. The combination of small size, and high surge capability makes them ideal for use in applications such as cellular phones, LCD displays, USB, and multi media card interfaces.

### Circuit Diagram



Transparent bottom view

### Features

- \* 5500W peak pulse power (8/20us)
- \* Operating voltage: 12V
- \* Ultra low clamping voltage
- \* One power line protects
- \* Complies with following standards:
  - IEC 61000-4-2 (ESD) immunity test
    - Air discharge:  $\pm 30\text{kV}$
    - Contact discharge:  $\pm 30\text{kV}$
  - IEC61000-4-5 (Lightning) 200A (8/20us)
- \* RoHS Compliant
- \* Package: DFN2020-3
- \* Lead Finish: NiPdAu

### Applications

- \* Power Management
- \* Industrial Application
- \* Power Supply Protection
- \* Many other portable devices

### Ordering Information

Part Number	Packaging	Reel Size
JS12U1GD50-3	3000/Tape & Reel	7 inch

**Absolute Maximum Ratings ( $T_A=25^{\circ}\text{C}$  unless otherwise specified)**

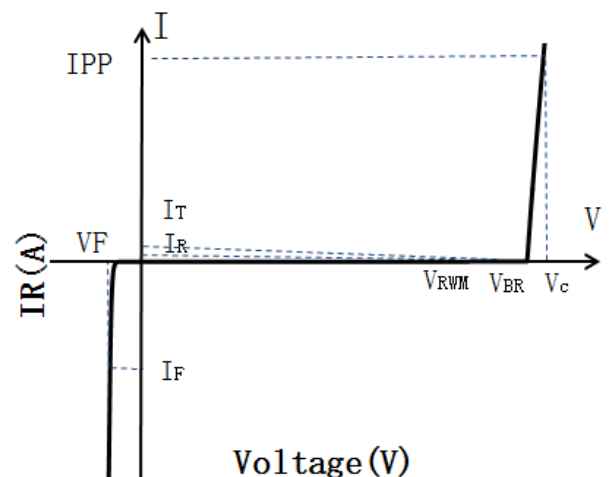
Parameter	Symbol	Value	Unit
Peak Pulse Power (8/20 $\mu\text{s}$ )	Ppk	5500	W
Peak Pulse Current (8/20 $\mu\text{s}$ )	IPP	200	A
ESD per IEC 61000-4-2 (Air)	VESD	$\pm 30$	kV
ESD per IEC 61000-4-2 (Contact)		$\pm 30$	
Operating Temperature Range	TJ	-55 to +125	$^{\circ}\text{C}$
Storage Temperature Range	Tstg	-55 to +150	$^{\circ}\text{C}$

**Electrical Characteristics ( $T_A=25^{\circ}\text{C}$  unless otherwise specified)**

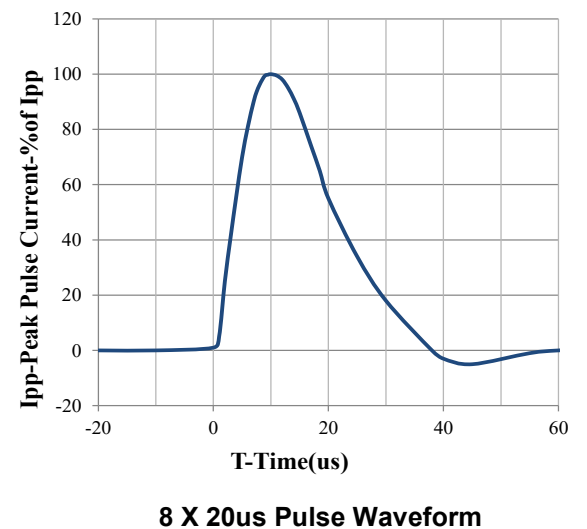
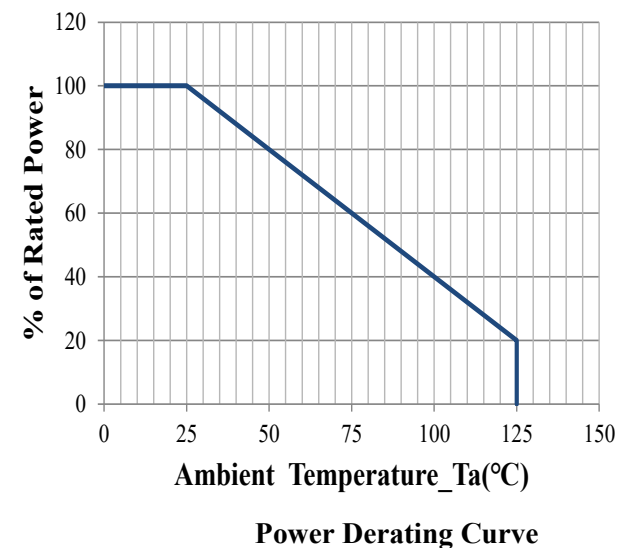
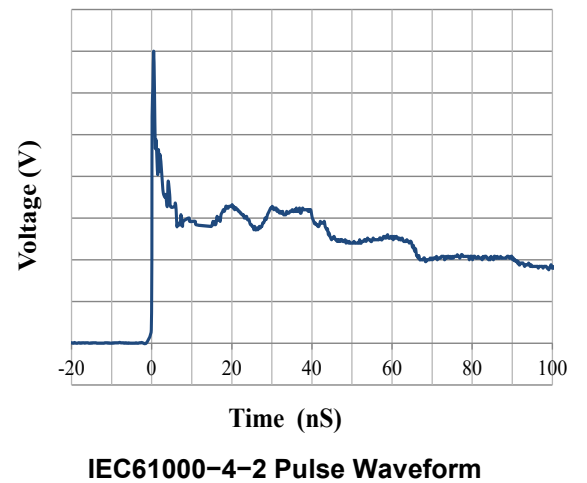
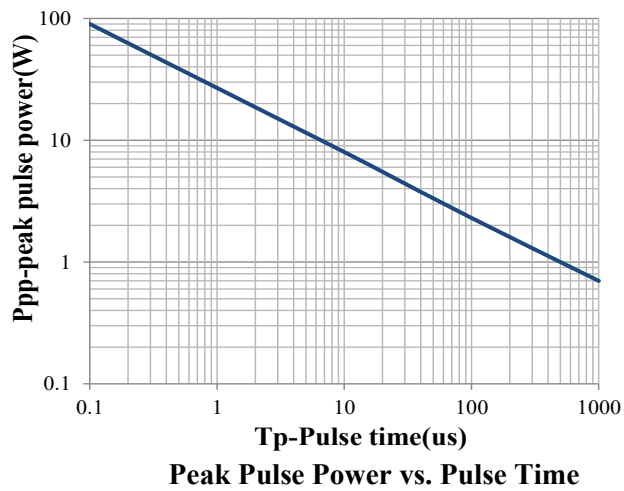
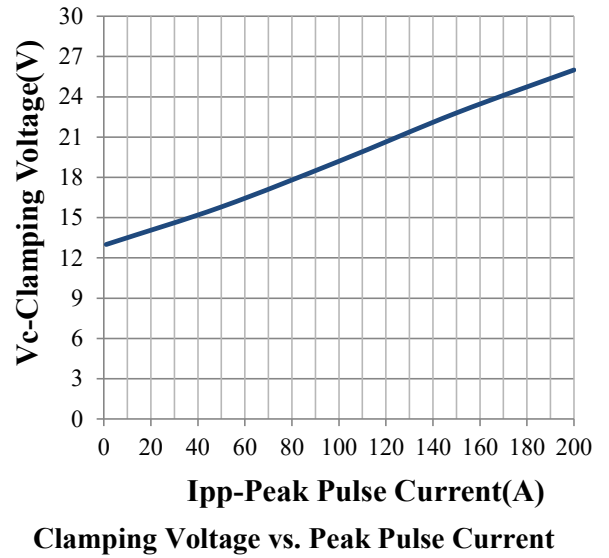
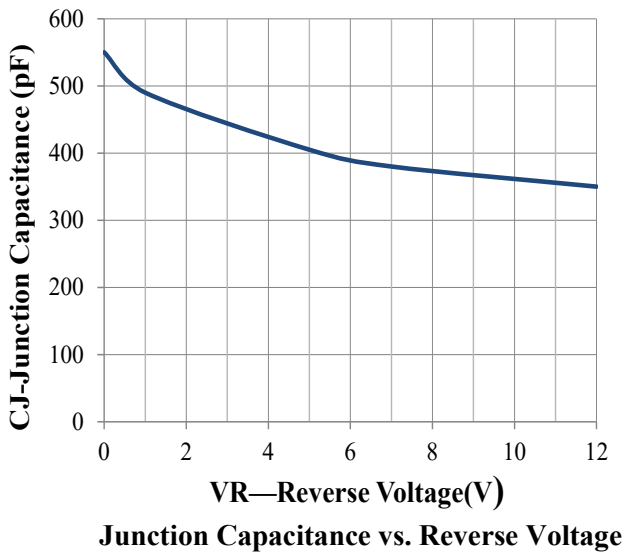
Parameter	Symbol	Test Condition	Min	Typ	Max	Unit
Reverse Working Voltage	$V_{RWM}$				12	V
Breakdown Voltage	$V_{BR}$	$I_T = 1\text{mA}$	12.0	13.0	15.0	V
Reverse Leakage Current	$I_R$	$V_{RWM} = 12\text{V}$			1.0	$\mu\text{A}$
Clamping Voltage	$V_C$	$I_{PP} = 150\text{A}$ (8 x 20 $\mu\text{s}$ pulse)		22.0		V
Clamping Voltage	$V_C$	$I_{PP} = 200\text{A}$ (8 x 20 $\mu\text{s}$ pulse)		27.0		V
Junction Capacitance	$C_J$	$V_R = 0\text{V}$ , $f = 1\text{MHz}$		550		pF

**Portion Electronics Parameter**

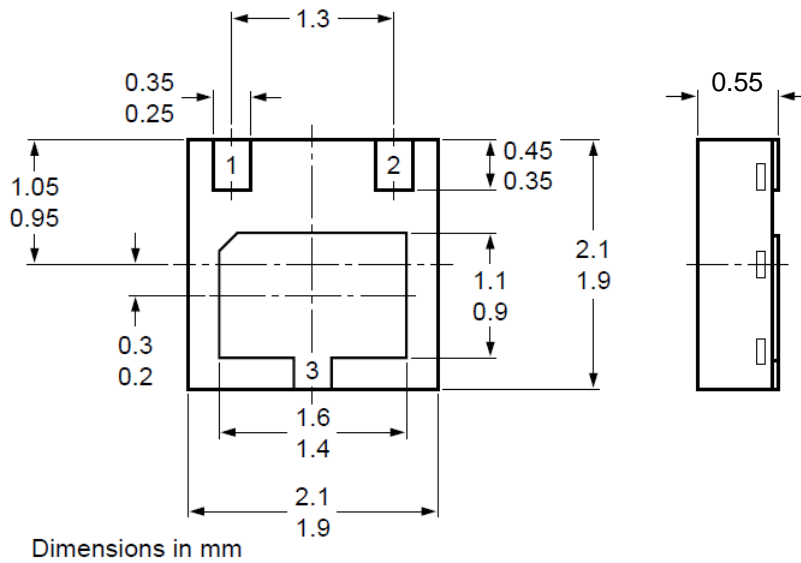
Symbol	Parameter
$I_T$	Test Current
$I_{PP}$	Maximum Reverse Peak Pulse Current
$V_C$	Clamping Voltage @ $I_C$
$I_F$	Forward Current
$V_F$	Forward Voltage @ $I_F$



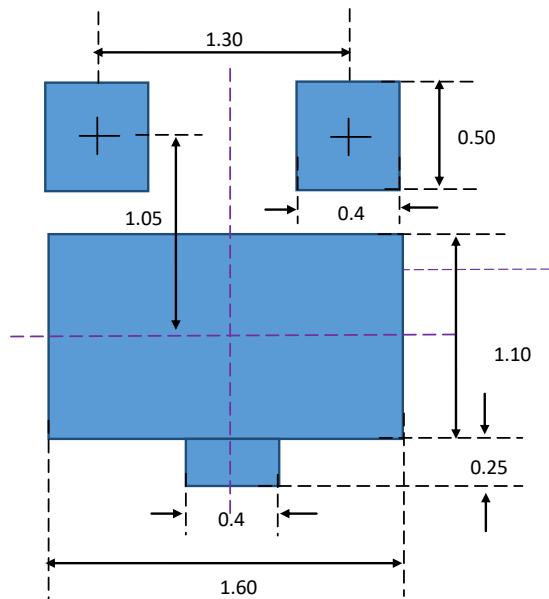
Typical Performance Characteristics ( $T_A=25^\circ\text{C}$  unless otherwise Specified)



DFN2020-3 Package Outline Drawing



Suggested Land Pattern



NOTICE

Jelan-Link reserves the right to make changes without further notice to any products here in.

Only obligations are those in the Jelan-Link Standard Terms and Conditions of Sale and in no case will Jelan-Link be liable for any incidental, indirect, or consequential damages arising from the sale, resale, use, or misuse of its products.